

## EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L35	182	(crystalline near alloy) with (si silicon silicide)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/11/26 15:23
L36	1	L35 and (tft (thin near film near transistor))	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/11/26 15:21
L37	0	("2005/0164520").URPN.	USPAT	OR	ON	2006/11/26 15:21
L38	1	L35 and ("349"/\$.ccls.)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/11/26 15:22
L39	150	(crystalline adj alloy) with (si silicon silicide)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/11/26 15:23

## EAST Search History

L40	39	(US-20060255462-\$ or US-20060151788-\$ or US-20050026424-\$ or US-20030211719-\$ or US-20030032284-\$ or US-20040171203-\$ or US-20020057412-\$ or US-20020008797-\$ or US-20020043660-\$ or US-20010022364-\$ or US-20030214043-\$ or US-20040238864-\$ or US-20060079154-\$ or US-20060263949-\$ or US-20060055065-\$ or US-20050029663-\$ or US-20040150120-\$ or US-20040141130-\$ or US-20040051100-\$ or US-20010040645-\$ or US-20010026331-\$ or US-20040206958-\$ or US-20030094615-\$ or US-20040119955-\$ or US-20040217347-\$ or US-20040084670-\$).did. or (US-20030001266-\$).did. or (US-6887776-\$ or US-6743716-\$ or US-6787446-\$ or US-6688584-\$ or US-6838772-\$ or US-5821562-\$ or US-6268659-\$ or US-6617644-\$ or US-6057897-\$ or US-5541748-\$ or US-6756679-\$ or US-6075293-\$). did.	US-PGPUB; USPAT	OR	ON	2006/11/26 15:43
L41	35	L40 and silicide	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/11/26 16:01
L42	9	L40 and (silicide with (barrier diffus\$3))	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/11/26 15:44

## EAST Search History

L43	7	"507964".ap.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/11/26 15:44
L44	1	L43 and (silicide with (barrier diffus\$3))	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/11/26 15:57
L45	1	L43 and (silicide same (barrier diffus\$3))	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/11/26 15:57
L46	3	("2002018258").PN.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/11/26 16:03
L47	2	"20020182858".pn.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/11/26 16:04
L48	68	silicide with (diffusion near barrier) with (improv\$5 advantag\$5)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/11/26 16:34
L49	1	L48 and (tft (thin near film near transistor))	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/11/26 16:27

## EAST Search History

L50	7	((titanium near silicide) with (diffusion near barrier) with (improv\$5 advantag\$5))	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/11/26 16:41
L51	37	((titanium near silicide) with (diffusion near barrier)) same (improv\$5 advantag\$5)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/11/26 16:56
L52	4	((titanium near salicide) with (diffusion near barrier)) same (improv\$5 advantag\$5)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/11/26 16:50
L53	18	((metal near silicide) with (diffusion near barrier)) with (improv\$5 advantag\$5)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/11/26 17:06
L54	1	"6613670".pn. and (silicide)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/11/26 17:00
L55	68	(( silicide) with (diffusion near barrier)) with (improv\$5 advantag\$5)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/11/26 17:18
L56	160	((titanium near (salicide silicide)) with (diffus\$3 near barrier))	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/11/26 17:19

## EAST Search History

L57	42	(US-20060255462-\$ or US-20060151788-\$ or US-20050026424-\$ or US-20030211719-\$ or US-20030032284-\$ or US-20040171203-\$ or US-20020057412-\$ or US-20020008797-\$ or US-20020043660-\$ or US-20010022364-\$ or US-20030214043-\$ or US-20040238864-\$ or US-20060079154-\$ or US-20060263949-\$ or US-20060055065-\$ or US-20050029663-\$ or US-20040150120-\$ or US-20040141130-\$ or US-20040051100-\$ or US-20010040645-\$ or US-20010026331-\$ or US-20040206958-\$ or US-20030094615-\$ or US-20040119955-\$ or US-20040217347-\$ or US-20040084670-\$).did. or (US-20030001266-\$ or US-20020182858-\$).did. or (US-6887776-\$ or US-6743716-\$ or US-6787446-\$ or US-6688584-\$ or US-6838772-\$ or US-5821562-\$ or US-6268659-\$ or US-6617644-\$ or US-6057897-\$ or US-5541748-\$ or US-6756679-\$ or US-6075293-\$ or US-6406998-\$ or US-7030012-\$). did.	US-PGPUB; USPAT	OR	ON	2006/11/26 17:35
L58	22	L57 and ((diffus\$3 barrier) with angstrom nm)	US-PGPUB; USPAT	OR	ON	2006/11/26 17:36
L59	22	L57 and ((diffus\$3 barrier) with angstrom nm)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/11/26 17:36
L60	8	L57 and ((diffus\$3 barrier) with (angstrom nm))	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/11/26 17:38

## EAST Search History

L61	34	(tft (thin near film near transistor)) and ((diffusion near barrier) with (angstrom nm))	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/11/26 17:50
L62	0	(tft (thin near film near transistor)) and ((diffusion near barrier) with (angstrom nm) with (improv\$5 advantage\$4))	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/11/26 17:41
L63	0	(tft (thin near film near transistor)) and ((diffusion near barrier) with (". ang"))	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/11/26 17:51
L64	0	(tft (thin near film near transistor)) and ((diffusion near barrier) with (". angs"))	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/11/26 17:51
L65	0	(tft (thin near film near transistor)) and ((diffusion near barrier) with (". ang."))	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/11/26 17:51
L66	0	(tft (thin near film near transistor)) and ((diffusion near barrier) with (". ang."))	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/11/26 17:52
L67	0	((diffusion near barrier) with (".ang."))	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/11/26 17:52

## EAST Search History

L68	0	((diffusion near barrier) with ".ang.")	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/11/26 17:52
L69	0	((diffusion near barrier) with ".ang")	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/11/26 17:52
L70	503	((diffusion near barrier) with "ang")	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/11/26 17:52
L71	13	(tft (thin near film near transistor)) and ((diffusion near barrier) with (ang))	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/11/26 17:53
S1	11281	((257/59,72,751,767,E27.131) or (349/42,43,46,139,143,147)).CCLS.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/11/22 13:34
S2	120429	TFT (thin near film near transistor)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/11/25 18:00
S3	1722	silicide same (diffusion near barrier)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/11/22 13:35

## EAST Search History

S4	89329	(copper Cu) near alloy	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/11/22 13:36
S5	145775	(gate scan\$4) near (line\$1 bus\$2)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/11/22 13:36
S6	295045	(source data) near (line\$1 bus\$2)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/11/22 13:37
S7	748	S3 same substrate	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/11/22 13:37
S8	1	S2 and S4 and S5 and S6 and S7	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/11/22 13:37
S9	10	S2 and S4 and S7	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/11/22 13:41
S10	2051	S2 and S4	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/11/22 13:42

## EAST Search History

S11	60	S10 and (diffusion near barrier)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/11/22 13:43
S12	2	("20030001266").PN.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/11/26 15:20
S13	0	("L10and((coppercu)neardiffus\$3")).PN.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/11/22 13:54
S14	0	("L10and((coppercu)neardiffus\$3")).PN.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/11/22 13:54
S16	181	S10 and (silicide same substrate)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/11/22 13:54
S17	27	S10 and (((copper cu) and (si silicon silicide)) near diffus\$3)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/11/22 13:55
S18	1	("2003/0001266").URPN.	USPAT	OR	ON	2006/11/25 13:47

## EAST Search History

S19	150	("20010002333"   "20020014646"   "20020028552"   "20020096768"   "20020109233"   "2842438"   "3954570"   "4386116"   "4394223"   "4423547"   "4565157"   "4574095"   "4762728"   "4788082"   "4847111"   "4931410"   "4948459"   "4962058"   "4996584"   "5019531"   "5034799"   "5084412"   "5100499"   "5130274"   "5149615"   "5158986"   "5173442"   "5231056"   "5240878"   "5243222"   "5256205"   "5334356"   "5354712"   "5371042"   "5384284"   "5413687"   "5426330"   "5442237"   "5447887"   "5470789"   "5470801"   "5476817"   "5495667"   "5506449"   "5529956"   "5538922"   "5539060"   "5595937"   "5609721"   "5625232"   "5635253"   "5654245"   "5662788"   "5670420"   "5674787"   "5675187"   "5679608"   "5681441"   "5695810"   "5719089"   "5719410"   "5739579"   "5763953"   "5780358"   "5785570"   "5792522"   "5801098"   "5814557"   "5821168"   "5824599"   "5858877"   "5891797"   "5891804"   "5893752"   "5895740"   "5897370"   "5907772"   "5911113"   "5913147"   "5925930"   "5930669"   "5932928"   "5933758"   "5940733"   "5948467"   "5962923"   "5968333"   "5969422"   "5972179"   "5972804"   "5976710"   "5981350"   "5985759"   "5989623"   "5994777"   "6001730"   "6008117"   "6015465"   "6017820"   "6030877"   "6037248"   "6054172"   "6065424"   "6069068"   "6071810"   "6077792"   "6100193"   "6126989"   "6136095"   "6139699"   "6140228"   "6140234"   "6143646"   "6150261"   "6153507"   "6159769"   "6168704"   "6171661"   "6177350"   "6183564"   "6187656"   "6190732"   "6197688").PN. OR ("6207222"   "6207553"   "6207558"   "6211049"   "6211073"   "6221763"   "6232219"   "6249056"   "6265311"   "6271592"   "6284656"   "6287954"   "6323553"   "6326303"   "6342448"   "6359328"   "6372622"   "6376370"   "6383920"   "6387542"   "6399480"   "6403481"   "6420262")	US-PGPUB; USPAT; USOCR	OR	ON	2006/11/25 13:55
11/26/2006 6:16:20 PM	C:\Documents and Settings\Volat\My Documents\EAST\Workspaces\10535304.wsp				Page 10	

## EAST Search History

S20	0	("2002/0041031").URPN.	USPAT	OR	ON	2006/11/25 14:44
S21	120582	TFT (thin near film near transistor)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/11/25 14:47
S22	89420	(copper Cu) near alloy	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/11/25 14:47
S23	2064	S21 and S22	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/11/25 15:59
S24	76	S23 and ((copper cu) near diffus\$3)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/11/25 14:47
S25	33	("20010023771"   "20010055851"   "20020127833"   "20020127836"   "20030038037"   "20030104649"   "20030116439"   "20040026786"   "5235139"   "5370766"   "5380560"   "5510216"   "5529863"   "5545927"   "5755859"   "5789320"   "5871655"   "5898222"   "6091488"   "6114097"   "6180523"   "6255187"   "6265086"   "6326303"   "6426281"   "6436816"   "6486530"   "6515336"   "6624473"   "6656827").PN. OR ("6887776").URPN.	US-PGPUB; USPAT; USOCR	OR	ON	2006/11/25 15:13
S26	2044	(diffus\$3 near barrier) with (silicon si silicide) with (zr ti hf v ta ni cr nb co mn mo w rh pd pt zirconium titanium hafnium vanadium tantalum nickel chromium niobium cobalt manganese molybdenum tungsten rhodium palladium platinum)	US-PGPUB; USPAT; USOCR	OR	ON	2006/11/25 15:29

## EAST Search History

S27	64	S26 and S21	US-PGPUB; USPAT; USOCR	OR	ON	2006/11/25 15:18
S28	40	S27 and (copper cu)	US-PGPUB; USPAT; USOCR	OR	ON	2006/11/25 15:18
S29	2	("5798299").PN. OR ("6838772").URPN.	US-PGPUB; USPAT; USOCR	OR	ON	2006/11/25 15:20
S30	3	("2003/0214043").URPN.	USPAT	OR	ON	2006/11/25 15:27
S31	6982	(diffus\$3 near barrier) with (zr ti hf v ta ni cr nb co mn mo w rh pd pt zirconium titanium hafnium vanadium tantalum nickel chromium niobium cobalt manganese molybdenum tungsten rhodium palladium platinum)	US-PGPUB; USPAT; USOCR	OR	ON	2006/11/25 15:48
S32	169	S31 and S21	US-PGPUB; USPAT; USOCR	OR	ON	2006/11/25 15:31
S33	117	S32 and (copper cu)	US-PGPUB; USPAT; USOCR	OR	ON	2006/11/25 15:31
S34	77	S33 not S28	US-PGPUB; USPAT; USOCR	OR	ON	2006/11/25 15:31
S35	17	("20030020088"   "3685028"   "4663270"   "5589692"   "5953628"   "6055180"   "6272038"   "6314019"   "6320200"   "6324091"   "6326640"   "6348700"   "6395642"   "6452207"   "6541816"   "6555436"   "6740900").PN. OR ("6977389").URPN.	US-PGPUB; USPAT; USOCR	OR	ON	2006/11/25 15:35
S36	13	("20020096681" "20020123220" "5932907" "6211084" "6329701").PN.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/11/25 15:47
S37	0	"L13" and ((diffus\$3 near barrier) same (zr ti hf v ta ni cr nb co mn mo w rh pd pt zirconium titanium hafnium vanadium tantalum nickel chromium niobium cobalt manganese molybdenum tungsten rhodium palladium platinum)) and (copper cu)	US-PGPUB; USPAT; USOCR	OR	ON	2006/11/25 15:50

## EAST Search History

S38	0	"L13" and (diffus\$3 near barrier) and (copper cu)	US-PGPUB; USPAT; USOCR	OR	ON	2006/11/25 15:49
S39	438	"L13" and (silicon silicide si) and (copper cu)	US-PGPUB; USPAT; USOCR	OR	ON	2006/11/25 15:50
S40	3	S36 and ((diffus\$3 near barrier) same (zr ti hf v ta ni cr nb co mn mo w rh pd pt zirconium titanium hafnium vanadium tantalum nickel chromium niobium cobalt manganese molybdenum tungsten rhodium palladium platinum)) and (copper cu)	US-PGPUB; USPAT; USOCR	OR	ON	2006/11/25 15:53
S41	2	S40 and ((cu copper) with (gate source bit line))	US-PGPUB; USPAT; USOCR	OR	ON	2006/11/25 15:52
S42	2	S36 and ((diffus\$3 near barrier) same (zr ti hf v ta ni cr nb co mn mo w rh pd pt zirconium titanium hafnium vanadium tantalum nickel chromium niobium cobalt manganese molybdenum tungsten rhodium palladium platinum)) and ((copper cu) with (source gate bit line))	US-PGPUB; USPAT; USOCR	OR	ON	2006/11/25 15:53
S43	184	S23 and (silicide same substrate)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/11/25 16:00
S44	184	S43 and (copper cu)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/11/25 16:00
S45	142	S44 and (diffus\$3 barrier)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/11/25 16:01

## EAST Search History

S46	4	"988962".ap.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/11/25 16:01
S47	33	("20010023771"   "20010055851"   "20020127833"   "20020127836"   "20030038037"   "20030104649"   "20030116439"   "20040026786"   "5235139"   "5370766"   "5380560"   "5510216"   "5529863"   "5545927"   "5755859"   "5789320"   "5871655"   "5898222"   "6091488"   "6114097"   "6180523"   "6255187"   "6265086"   "6326303"   "6426281"   "6436816"   "6486530"   "6515336"   "6624473"   "6656827").PN. OR ("6887776").URPN.	US-PGPUB; USPAT; USOCR	OR	ON	2006/11/25 16:06
S48	0	("2006/0263949").URPN.	USPAT	OR	ON	2006/11/25 16:41
S49	120582	TFT (thin near film near transistor)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/11/25 18:00
S50	6027	(349/42,43,46,139,143,147).CCLS.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/11/25 18:01
S51	3862	S49 and S50	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/11/25 18:01
S52	650	S51 and (copper cu)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/11/25 18:01

## EAST Search History

S53	37	S52 and (silicide same (barrier diffus\$3))	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/11/25 18:25
S54	1	("2004/0141130").URPN.	USPAT	OR	ON	2006/11/25 18:22
S55	2	jp-2003321783-\$ did.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/11/25 18:22
S56	2	jp-2002318624-\$ did.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/11/25 18:23
S57	0	"318624"	JPO	OR	ON	2006/11/25 18:23
S58	0	"2002-318624"	JPO	OR	ON	2006/11/25 18:23
S59	3	"2002318624"	JPO	OR	ON	2006/11/25 18:23
S60	84	S52 and silicide and (barrier diffus\$3)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/11/25 18:25
S61	47	S60 not S53	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/11/25 18:38
S62	5832	(257/59,72,751,767,E27.131).CCLS.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/11/25 18:38

## EAST Search History

S63	3066	S62 and (tft (thin near film near transistor))	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/11/25 18:38
S64	1025	S63 and (copper cu)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/11/25 18:39
S65	40	S64 and (silicide same (diffus\$3 barrier))	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/11/25 19:01
S66	11	("3607379"   "3729807"   "4463059"   "4620215"   "4772935"   "4954870"   "5289016"   "5514912"   "5532183"   "5855993"   "5901901").PN. OR ("6268659").URPN.	US-PGPUB; USPAT; USOCR	OR	ON	2006/11/25 19:00
S67	2009	438/149.ccls.	US-PGPUB; USPAT; USOCR	OR	ON	2006/11/25 19:00
S68	1322	S67 and (tft (thin near film near transistor))	US-PGPUB; USPAT; USOCR	OR	ON	2006/11/25 19:00
S69	509	S68 and (copper cu)	US-PGPUB; USPAT; USOCR	OR	ON	2006/11/25 19:00
S70	155	S69 and (silicide and (diffus\$3 barrier))	US-PGPUB; USPAT; USOCR	OR	ON	2006/11/25 19:01
S71	275	S64 and (silicide and (diffus\$3 barrier))	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/11/25 19:01

## EAST Search History

S72	235	S71 not S65	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/11/25 19:02
S73	369	S70 S72	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/11/25 19:02